

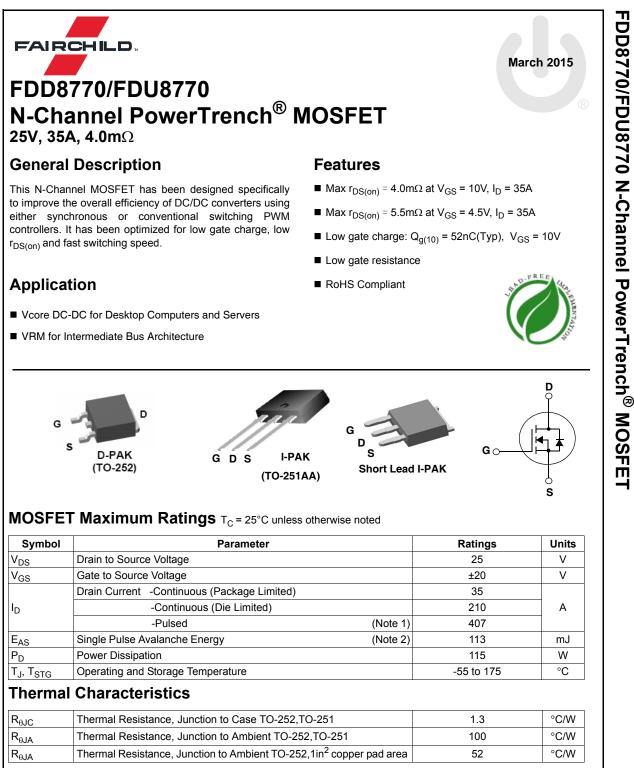
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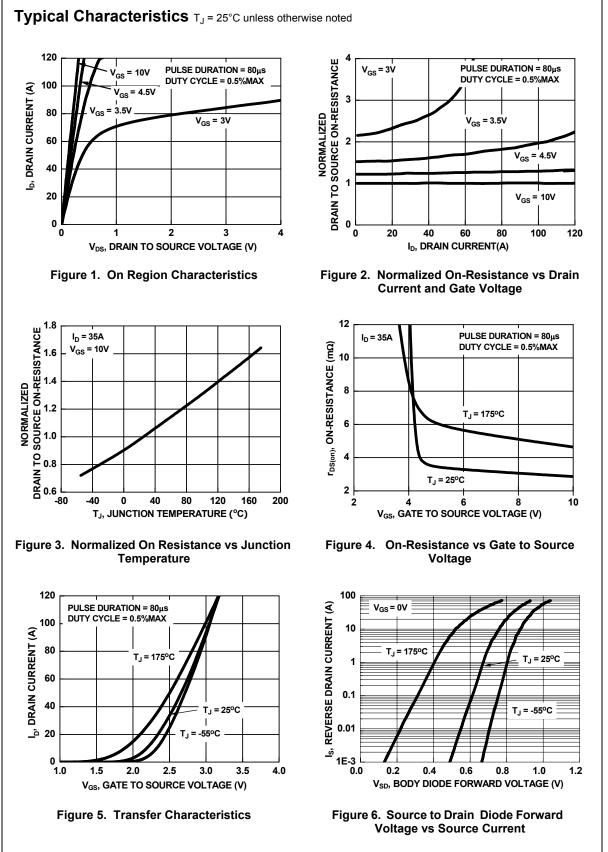
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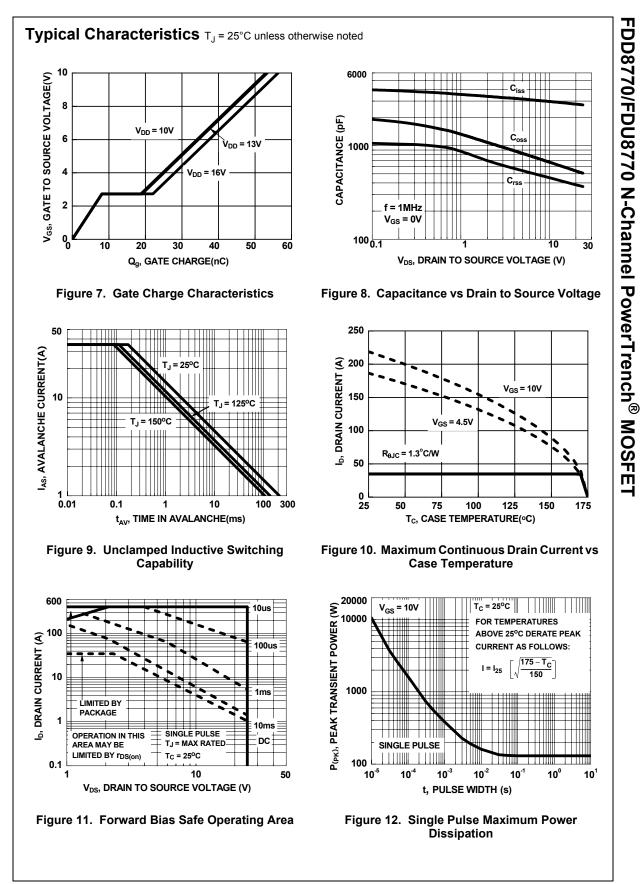


## Package Marking and Ordering Information

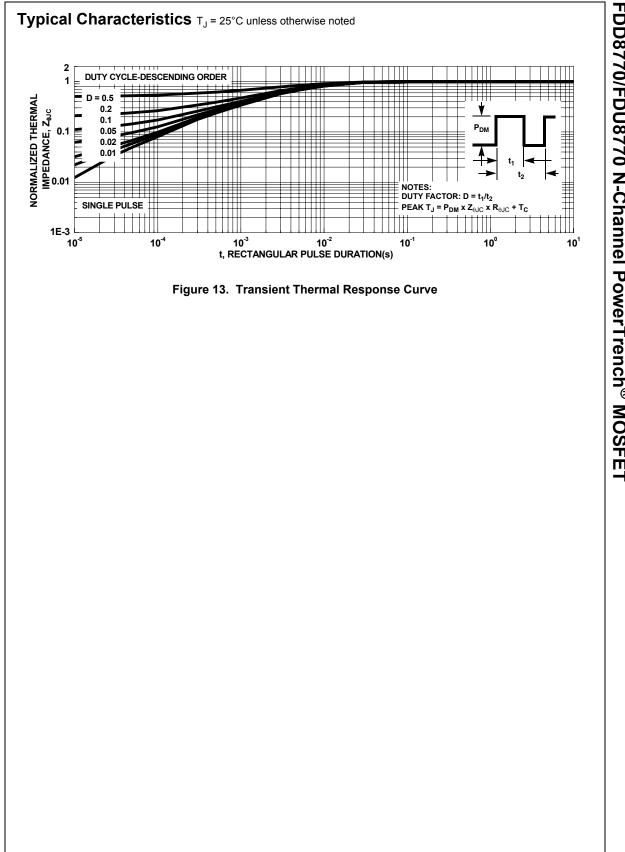
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8770	FDD8770	TO-252AA	13"	16mm	2500 units
FDU8770	FDU8770	TO-251AA	N/A(Tube)	N/A	75 units
FDU8770	FDU8770_F071	TO-251AA	N/A(Tube)	N/A	75 units

Symbol	Parameter	Test Conditions		Тур	Max	Units
Off Chara	cteristics					
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V				V
ΔB <sub>VDSS</sub>	Breakdown Voltage Temperature	$I_D = 250 \mu A$ , referenced to		13.6		mV/°C
$\Delta T_J$	Coefficient	25°C				
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 20V,			1	μA
088	° °	$V_{GS} = 0V$ $T_J = 150^{\circ}C$			250	
I <sub>GSS</sub>	Gate to Source Leakage Current	V <sub>GS</sub> = ±20V			±100	nA
On Chara	cteristics					
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250 \mu A$	1.2	1.6	2.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_{.l}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$ , referenced to $25^{\circ}C$		-5.9		mV/°C
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 35A		3.3 4.0		
	Desig to Course On Desigtance	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 35A			5.5	
	Drain to Source On Resistance	$V_{GS} = 10V, I_D = 35A$ T <sub>1</sub> = 175°C		4.8	5.9	mΩ
C <sub>oss</sub> C <sub>rss</sub>	Output Capacitance Reverse Transfer Capacitance	v <sub>DS</sub> = 13V, v <sub>GS</sub> = 0V, -f = 1MHz		685 450	915 675	pF pF
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 13V, V <sub>GS</sub> = 0V,		2795	3720 915	pF pF
		f = 1MHz		450	675	ρ- Ω
R <sub>g</sub>	Gate Resistance			1.5		52
Switching	g Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time			10	20	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 13V, I <sub>D</sub> = 35A V <sub>GS</sub> = 10V, R <sub>GS</sub> = 5Ω		12	22	ns
	Turn-Off Delay Time	$v_{\rm GS} = 10v, R_{\rm GS} = 522$		49	78	ns
t <sub>d(off)</sub>				25	40	ns
	Fall Time			52	73	nC
t <sub>f</sub>	Fall Time Total Gate Charge	$V_{GS} = 0V$ to $10V$ $V_{GS} = 12V$				nC
t <sub>d(off)</sub> t <sub>f</sub> Q <sub>g</sub> Q <sub>g</sub>		$V_{\text{DD}} = 0V \text{ to } 5V$ $V_{\text{DD}} = 13V$		29	41	
t <sub>f</sub> Q <sub>g</sub>	Total Gate Charge	$V_{GS} = 0V \text{ to } 5V$ $V_{DD} = 13V$ $I_D = 35A$		8.1	41	nC
t <sub>f</sub> Q <sub>g</sub> Q <sub>g</sub> Q <sub>gs</sub>	Total Gate Charge Total Gate Charge	$V_{\text{DD}} = 0V \text{ to } 5V$ $V_{\text{DD}} = 13V$			41	nC nC
t <sub>f</sub> Q <sub>g</sub> Q <sub>g</sub> Q <sub>gs</sub> Q <sub>gd</sub>	Total Gate Charge         Total Gate Charge         Gate to Source Gate Charge	$V_{GS} = 0V \text{ to } 5V$ $V_{DD} = 13V$ $I_D = 35A$		8.1	41	
t <sub>f</sub> Q <sub>g</sub> Q <sub>gs</sub> Q <sub>gd</sub> Drain-Sou	Total Gate Charge         Total Gate Charge         Gate to Source Gate Charge         Gate to Drain "Miller"Charge         urce Diode Characteristics	$V_{GS} = 0V \text{ to } 5V$ $V_{DD} = 13V$ $I_D = 35A$		8.1	41	nC
t <sub>f</sub> Q <sub>g</sub> Q <sub>gs</sub> Q <sub>gd</sub> Drain-Sou	Total Gate ChargeTotal Gate ChargeGate to Source Gate ChargeGate to Drain "Miller"Charge	$V_{GS} = 0V \text{ to } 5V$ $V_{DD} = 13V$ $I_D = 35A$ $I_g = 1.0mA$		8.1 11		
t <sub>f</sub> Q <sub>g</sub> Q <sub>g</sub> Q <sub>gs</sub> Q <sub>gd</sub>	Total Gate Charge         Total Gate Charge         Gate to Source Gate Charge         Gate to Drain "Miller"Charge         urce Diode Characteristics	$V_{GS} = 0V \text{ to } 5V$ $I_D = 35A$ $I_g = 1.0mA$ $V_{GS} = 0V, I_S = 35A$		8.1 11 0.84	1.25	nC





FDD8770/FDU8770 Rev. 1.2







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